

WHAT IS CLAIMED IS:

1. An amplifier comprising:
a front amplification stage; and
a rear amplification stage which amplifies output
5 signal of said front amplification stage, said rear
amplification stage being disposed immediately after said
front amplification stage, said rear amplification stage
including a plurality of amplification unit connected in
parallel, wherein amplification unit that forms a part of
10 the plurality of amplification unit perform on/off switching
of amplification operation according to an RF input of the
front amplification stage or increase a bias current as the
RF input increases.
- 15 2. An amplifier comprising:
a front stage transistor supplied with an RF signal;
an inter-stage matching circuit;
a rear stage transistor group having a plurality of
transistors connected in parallel and supplied with an output
20 signal of said front stage transistor via said inter-stage
matching circuit; and
a rear stage DC bias control circuit which controls
a bias of a transistor that forms a part of said rear stage
transistor group according to an input level of the RF signal.

3. The amplifier according to claim 2, wherein said rear stage DC bias control circuit is connected between an emitter of said front stage transistor and a base of a transistor included in said rear stage transistor group and supplied with a bias controlled by said rear stage DC bias control circuit.

4. The amplifier according to claim 3, wherein said rear stage DC bias control circuit comprises AC blocking inductors connected in series between the emitter and the base, and a shunt resistor.

5. The amplifier according to claim 3, wherein said rear stage DC bias control circuit comprises an AC blocking inductor and a resistor connected in series between the emitter and the base, and a shunt resistor.

6. The amplifier according to claim 3, wherein said rear stage DC bias control circuit includes resistors connected in series between the emitter and the base, and a shunt resistor.

7. The amplifier according to claim 3, wherein said rear stage DC bias control circuit includes an AC blocking inductor and a resistor connected in series between the

emitter and the base, and a shunt diode.

8. The amplifier according to claim 3, wherein said rear stage DC bias control circuit includes resistors connected
5 in series between the emitter and the base, and a shunt diode.

9. The amplifier according to claim 2, wherein said rear stage DC bias control circuit is connected between a source of said front stage transistor and a gate of a transistor
10 included in said rear stage transistor group and supplied with a bias controlled by said rear stage DC bias control circuit.

10. The amplifier according to claim 9, wherein said rear
15 stage DC bias control circuit includes AC blocking inductors connected in series between the source and the gate, and a shunt resistor.

11. The amplifier according to claim 9, wherein said rear
20 stage DC bias control circuit includes an AC blocking inductor and a resistor connected in series between the source and the gate, and a shunt resistor.

12. The amplifier according to claim 9, wherein said rear
25 stage DC bias control circuit includes resistors connected

in series between the source and the gate, and a shunt resistor.

13. The amplifier according to claim 9, wherein said rear
5 stage DC bias control circuit includes an AC blocking inductor and a resistor connected in series between the source and the gate, and a shunt diode.

14. The amplifier according to claim 9, wherein said rear
10 stage DC bias control circuit includes resistors connected in series between the source and the gate, and a shunt diode.

15. The amplifier according to claim 2, wherein said rear
stage DC bias control circuit includes a control transistor
15 supplied with the RF signal, and said control transistor controls a bias of a transistor that forms a part of said rear stage transistor group according to an input level of the RF signal.

20 16. The amplifier according to claim 15, wherein said front group transistor, a transistor included in the rear transistor group and supplied with a fixed bias, and said control transistor are biased so as to perform operation of class AB.

25

17. The amplifier according to claim 15, wherein said rear stage DC bias control circuit further includes AC blocking inductors connected in series between an emitter of said control transistor and a base of a transistor included in said rear stage transistor group and supplied with a bias controlled by said rear stage DC bias control circuit, and a shunt resistor.

18. The amplifier according to claim 15, wherein said rear stage DC bias control circuit further includes an AC blocking inductor and a resistor connected in series between an emitter of said control transistor and a base of a transistor included in said rear stage transistor group and supplied with a bias controlled by said rear stage DC bias control circuit, and a shunt resistor.

19. The amplifier according to claim 15, wherein said rear stage DC bias control circuit further includes resistors connected in series between an emitter of said control transistor and a base of a transistor included in said rear stage transistor group and supplied with a bias controlled by said rear stage DC bias control circuit, and a shunt resistor.

20. The amplifier according to claim 15, wherein said rear

stage DC bias control circuit further includes an AC blocking inductor and a resistor connected in series between an emitter of said control transistor and a base of a transistor included in said rear stage transistor group and supplied with a bias controlled by said rear stage DC bias control circuit, and a shunt diode.

21. The amplifier according to claim 15, wherein said rear stage DC bias control circuit further includes resistors connected in series between an emitter of said control transistor and a base of a transistor included in said rear stage transistor group and supplied with a bias controlled by said rear stage DC bias control circuit, and a shunt diode.

22. The amplifier according to claim 15, wherein said rear stage DC bias control circuit further includes AC blocking inductors connected in series between a source of said control transistor and a gate of a transistor included in said rear stage transistor group and supplied with a bias controlled by said rear stage DC bias control circuit, and a shunt resistor.

23. The amplifier according to claim 15, wherein said rear stage DC bias control circuit further includes an AC blocking inductor and a resistor connected in series between a source

of said control transistor and a gate of a transistor included in said rear stage transistor group and supplied with a bias controlled by said rear stage DC bias control circuit, and a shunt resistor.

5

24. The amplifier according to claim 15, wherein said rear stage DC bias control circuit further includes resistors connected in series between a source of said control transistor and a gate of a transistor included in said rear stage transistor group and supplied with a bias controlled by said rear stage DC bias control circuit, and a shunt resistor.

25. The amplifier according to claim 15, wherein said rear stage DC bias control circuit further includes an AC blocking inductor and a resistor connected in series between a source of said control transistor and a gate of a transistor included in said rear stage transistor group and supplied with a bias controlled by said rear stage DC bias control circuit, and a shunt diode.

26. The amplifier according to claim 15, wherein said rear stage DC bias control circuit further includes resistors connected in series between a source of said control transistor and a gate of a transistor included in said rear

stage transistor group and supplied with a bias controlled by said rear stage DC bias control circuit, and a shunt diode.

27. The amplifier according to claim 2, wherein said front
5 stage transistor, said inter-stage matching circuit, said rear stage transistor group, and the rear group DC bias control circuit are integrated on same semiconductor chip.

28. The amplifier according to claim 2, wherein said front
10 stage transistor, said inter-stage matching circuit, said rear stage transistor group, and the rear group DC bias control circuit are provided distributively on two or more semiconductor chips.